

# **PSMN009-100P**

# N-channel TrenchMOS SiliconMAX standard level FET Rev. 4 — 27 December 2011 Product d

Product data sheet

#### **Product profile** 1.

## 1.1 General description

SiliconMAX standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

### 1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Suitable for high frequency applications due to fast switching characteristics

## 1.3 Applications

- High frequency computer motherboard DC-to-DC convertors
- OR-ing applicationss

## 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> ≥ 25 °C; T <sub>j</sub> ≤ 175 °C	-	-	100	V
$I_D$	drain current	$T_{mb}$ = 25 °C; $V_{GS}$ = 10 V; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	-	75	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; see <u>Figure 2</u>	-	-	230	W
Static char	acteristics					
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 25 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	7.5	8.8	mΩ
Dynamic c	Dynamic characteristics					
$Q_{GD}$	gate-drain charge	$V_{GS} = 10 \text{ V; } I_D = 75 \text{ A; } V_{DS} = 80 \text{ V;}$ $T_j = 25 \text{ °C; see } \frac{\text{Figure 11}}{\text{ or } 11 \text{ or } 11 $	-	44	-	nC



# 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain	mb	D
3	S	source		G (EX)
mb	D	mounting base; connected to drain	1 2 3	mbb076 S
			SOT78 (TO-220AB)	

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN009-100P	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> ≥ 25 °C; T <sub>j</sub> ≤ 175 °C	-	100	V
$V_{DGR}$	drain-gate voltage	$T_j \le 175 ^{\circ}\text{C}; T_j \ge 25 ^{\circ}\text{C}; R_{GS} = 20 \text{k}\Omega$	-	100	V
$V_{GS}$	gate-source voltage		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; see <u>Figure 1</u>	-	65	Α
		$V_{GS}$ = 10 V; $T_{mb}$ = 25 °C; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	75	Α
$I_{DM}$	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \text{ °C}$ ; see Figure 3	-	400	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; see <u>Figure 2</u>	-	230	W
T <sub>stg</sub>	storage temperature		-55	175	°C
T <sub>j</sub>	junction temperature		-55	175	°C
$V_{GSM}$	peak gate-source voltage	pulsed; $t_p \le 50 \mu s$ ; $T_j \le 150  ^{\circ}C$ ; $\delta = 25  \%$	-30	30	V
Source-dra	in diode				
Is	source current	T <sub>mb</sub> = 25 °C	-	75	Α
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \degree C$	-	400	Α
Avalanche	ruggedness				
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	$V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; $I_D$ = 35 A; $V_{sup}$ = 15 V; unclamped; $t_p$ = 0.1 ms; $R_{GS}$ = 50 $\Omega$	-	120	mJ
I <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche current	$V_{GS}$ = 10 V; $V_{sup}$ = 15 V; $R_{GS}$ = 50 $\Omega$ ; $T_{j(init)}$ = 25 °C; unclamped	-	75	Α

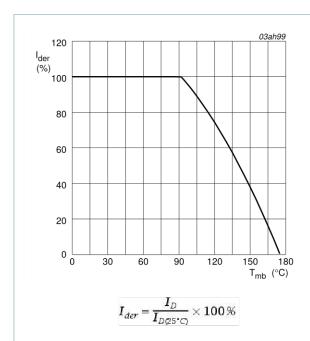
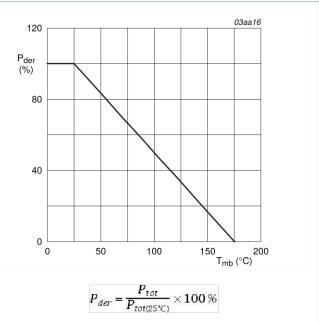
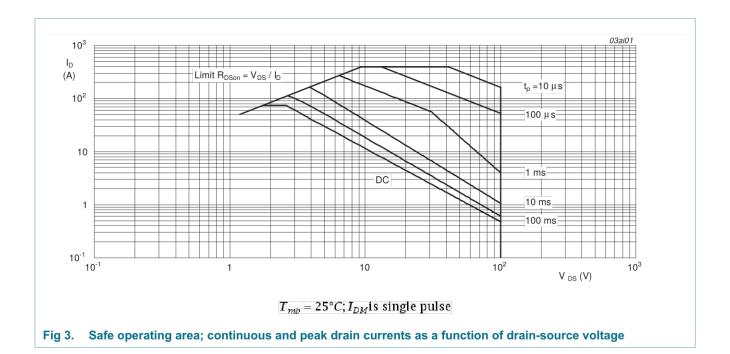


Fig 1. Normalized continuous drain current as a function of mounting base temperature



2. Normalized total power dissipation as a function of mounting base temperature

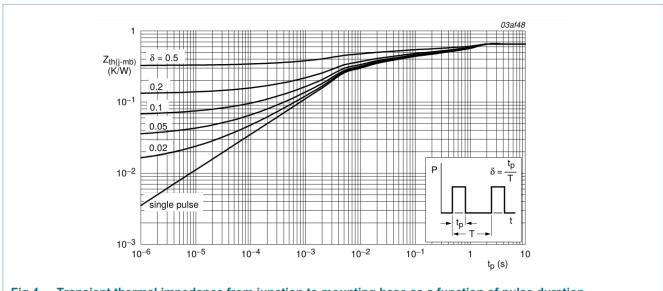
PSMN009-100P



## **Thermal characteristics**

Table 5. **Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	-	0.65	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	vertical in free air	-	60	-	K/W



Transient thermal impedance from junction to mounting base as a function of pulse duration

## 6. Characteristics

Table 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 ^{\circ}\text{C}$	90	-	-	V
		$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 175 °C; see <u>Figure 8</u>	1	-	-	V
		$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C; see <u>Figure 8</u>	2	3	4	V
		$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = -55 °C; see <u>Figure 8</u>	-	-	4.4	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$	-	-	500	μΑ
		$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	0.02	1	μΑ
$I_{GSS}$	gate leakage current	$V_{GS}$ = 20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	10	100	nΑ
		$V_{GS}$ = -20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	10	100	nΑ
$R_{DSon}$	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 175 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	20.25	23.8	mΩ
		$V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 25 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	7.5	8.8	mΩ
Dynamic o	characteristics					
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 75 A; V <sub>DS</sub> = 80 V; V <sub>GS</sub> = 10 V;	-	156	-	nC
$Q_{GS}$	gate-source charge	T <sub>j</sub> = 25 °C; see <u>Figure 11</u>	-	31	-	nC
$Q_{GD}$	gate-drain charge		-	44	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$	-	8250	-	рF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; see <u>Figure 12</u>	-	620	-	рF
C <sub>rss</sub>	reverse transfer capacitance		-	300	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 15 V; $R_L$ = 1.25 $\Omega$ ; $V_{GS}$ = 10 V;	-	38	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C; I_D = 12 A$	-	59	-	ns
$t_{d(off)}$	turn-off delay time		-	120	-	ns
t <sub>f</sub>	fall time		-	43	-	ns
Source-dr	ain diode					
$V_{SD}$	source-drain voltage	$I_S = 25 \text{ A}$ ; $V_{GS} = 0 \text{ V}$ ; $T_j = 25 ^{\circ}\text{C}$ ; see Figure 13	-	8.0	1.2	V

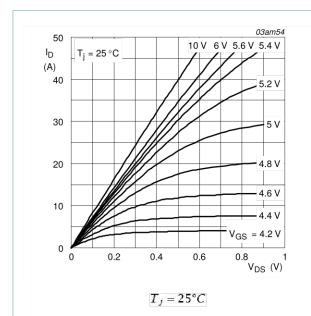


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

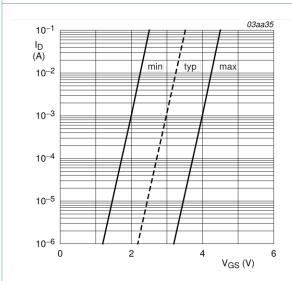


Fig 7. Sub-threshold drain current as a function of gate-source voltage

 $T_j = 25 \,^{\circ}C; V_{DS} = 5V$ 

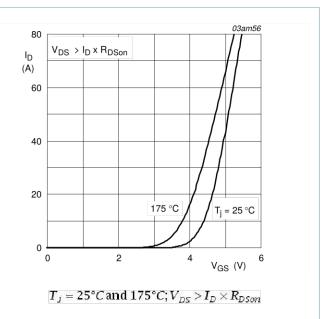


Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

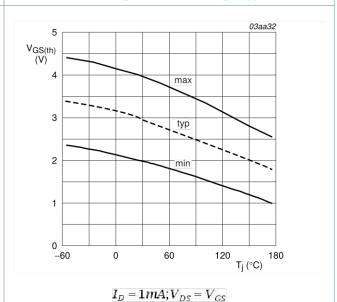
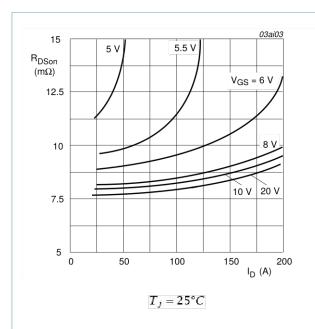


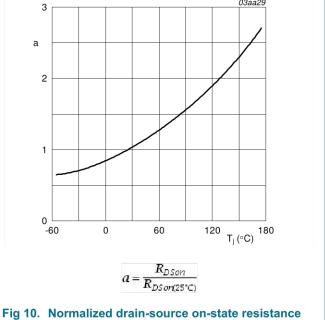
Fig 8. Gate-source threshold voltage as a function of junction temperature

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Drain-source on-state resistance as a function Fig 9. of drain current; typical values



factor as a function of junction temperature

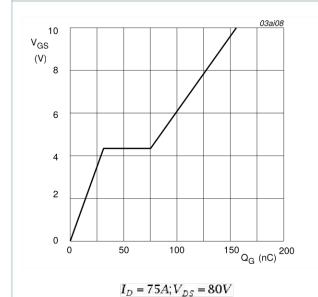


Fig 11. Gate-source voltage as a function of gate charge; typical values

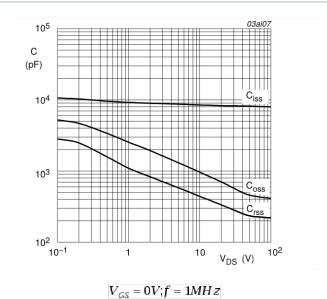


Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

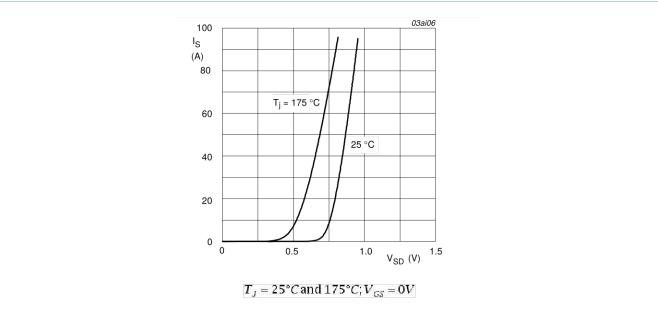
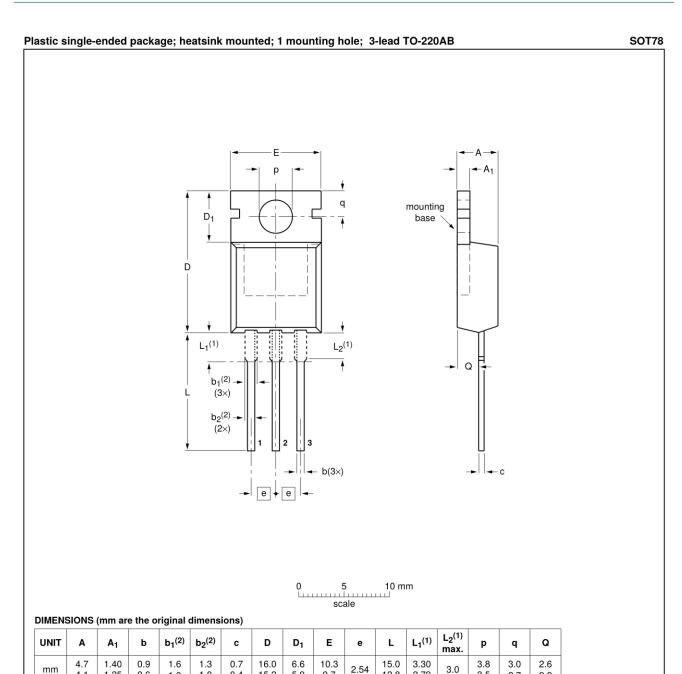


Fig 13. Source current as a function of source-drain voltage; typical values

## Package outline



## mm

1. Lead shoulder designs may vary.

4.1

2. Dimension includes excess dambar.

1.25

0.6

1.0

15.2

1.0

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT78		3-lead TO-220AB	SC-46		<del>08-04-23</del> 08-06-13	

Fig 14. Package outline SOT78 (TO-220AB)

PSMN009-100P

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2.2

# 8. Revision history

## Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN009-100P v.4	20111227	Product data sheet	-	PSMN009-100P v.3
Modifications:	<ul> <li>Various change</li> </ul>	es to content.		
PSMN009-100P v.3	20111121	Product data sheet	-	PSMN009-100P v.2

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Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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## **Nexperia**

## N-channel TrenchMOS SiliconMAX standard level FET

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